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Vishay General Semiconductor

# **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.36$  V at  $I_F = 5$  A

# **FEATURES**

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- · High efficiency operation
- · Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## **TYPICAL APPLICATIONS**

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

## **MECHANICAL DATA**

Case: D<sup>2</sup>PAK (TO-263AB) Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VB60100C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	100	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	60	А	
	per diode		30		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	320	А	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	







PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 30 A			
V <sub>RRM</sub>	100 V			
I <sub>FSM</sub>	320 A			
$V_F$ at $I_F = 30$ A	0.66 V			
T <sub>J</sub> max.	150 °C			
Package	D <sup>2</sup> PAK (TO-263AB)			
Circuit configuration	Common cathode			

# **TMBS**<sup>®</sup>

click logo to get started

FREE



**VB60100C** 



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ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	VF	0.45	-	V	
	I <sub>F</sub> = 10 A			0.52	-		
	I <sub>F</sub> = 15 A			0.58	0.63		
	I <sub>F</sub> = 20 A			0.63	-		
	I <sub>F</sub> = 30 A			0.73	0.79		
per diode <sup>(1)</sup>	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.36	-		
	I <sub>F</sub> = 10 A			0.45	-		
	I <sub>F</sub> = 15 A			0.53	0.58		
	I <sub>F</sub> = 20 A			0.58	-		
	I <sub>F</sub> = 30 A			0.66	0.70		
Reverse current at rated V <sub>R</sub> per diode <sup>(2)</sup>	V 80.V	T <sub>A</sub> = 25 °C	I <sub>R</sub>	24	500	μA	
	V <sub>R</sub> = 80 V	T <sub>A</sub> = 125 °C		13	20	mA	
	$V_{\rm R} = 100  \rm V$	T <sub>A</sub> = 25 °C		65	1000	μA	
		T <sub>A</sub> = 125 °C		30	-	mA	

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	VB60100C	UNIT	
Typical thermal resistance per diode	$R_{\theta JC}$	2.5	°C/W	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-263AB	VB60100C-M3/4W	1.38	4W	50/tube	Tube
TO-263AB	VB60100C-M3/8W	1.38	8W	800/reel	Tape and reel



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## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

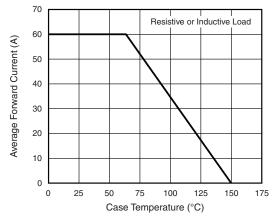


Fig. 1 - Forward Current Derating Curve

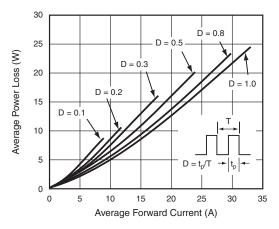


Fig. 2 - Forward Power Loss Characteristics Per Diode

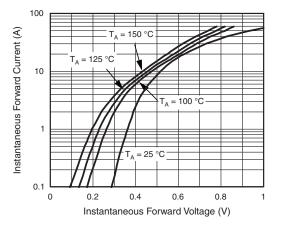


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

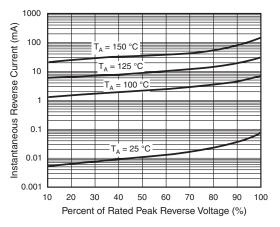


Fig. 4 - Typical Reverse Characteristics Per Diode

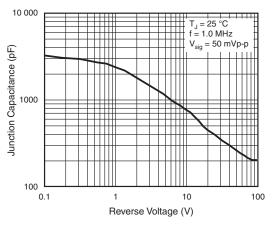


Fig. 5 - Typical Junction Capacitance Per Diode

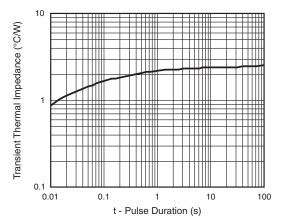


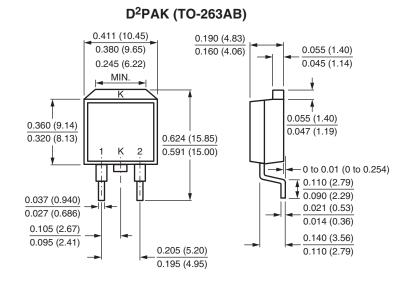
Fig. 6 - Typical Transient Thermal Impedance Per Diode

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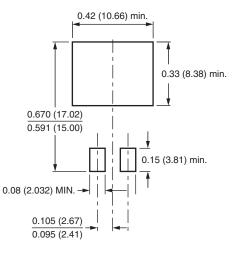


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## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



### **Mounting Pad Layout**





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